NPN MEDIUM POWER TRANSISTOR IN SOT23

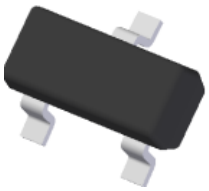
Features

- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type: MMBTA55 and MMBTA56
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An automotive-compliant part is available under a separate datasheet (MMBTA05Q/MMBTA06Q)**

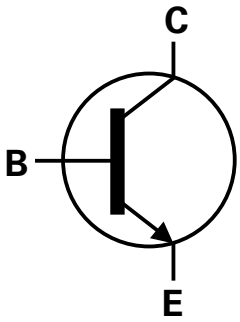
Mechanical Data

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.008 grams (Approximate)

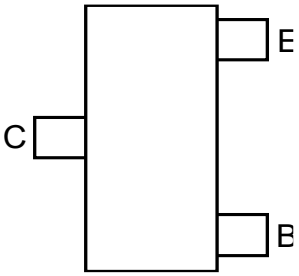
SOT23



Top View



Device Symbol



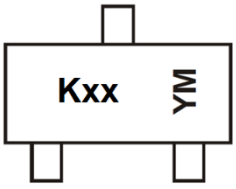
Top View
Pin Configuration

Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
MMBTA05-7-F	SOT23	K1G / K1H	7	8	3,000	Reel
MMBTA06-7-F	SOT23	K1G	7	8	3,000	Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



Kxx = Product Type Marking Code (See *Ordering Information*)
YM = Date Code Marking
Y or $\overline{Y}$ or $\underline{Y}$ = Year (ex: M = 2025)
M or $\overline{M}$ = Month (ex: 9 = September)

Date Code Key

Year	2005	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	S	-	M	N	P	R	S	T	U	V	W	X

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	MMBTA05	MMBTA06	Unit
Collector-Base Voltage	V_{CBO}	60	80	V
Collector-Emitter Voltage	V_{CEO}	60	80	V
Emitter-Base Voltage	V_{EBO}	4.0		V
Collector Current	I_C	500		mA
Peak Collector Current	I_{CM}	1		A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	310	mW
	(Note 6)		350	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	403	°C/W
	(Note 6)		357	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	350	°C/W
Thermal Resistance, Junction to Case	(Note 6)	$R_{\theta JC}$	72	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
6. Same as Note 5, except the device is mounted on 15mm x 15mm 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the leads).
8. Refer to JEDEC specifications JESD22-A114 and JESD22-A115.

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Thermal Characteristics and Derating Information

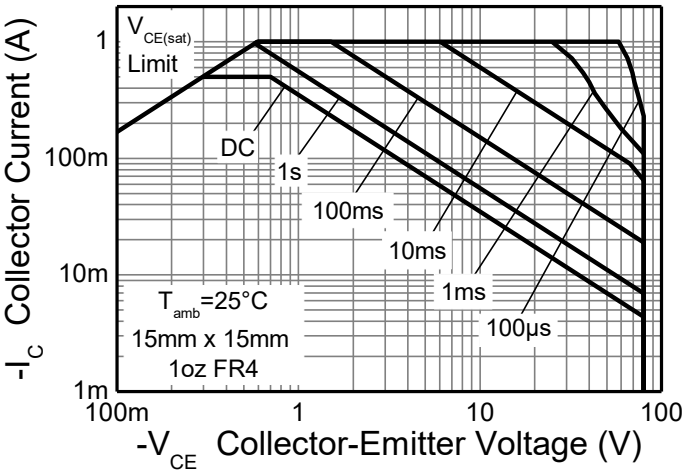


Figure 1. Safe Operating Area

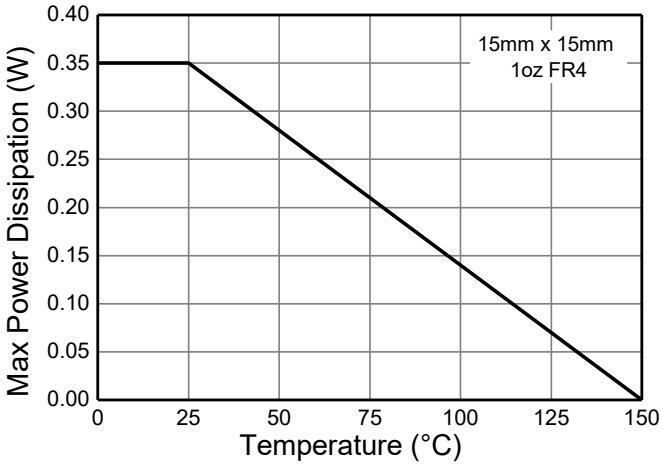


Figure 2. Derating Curve

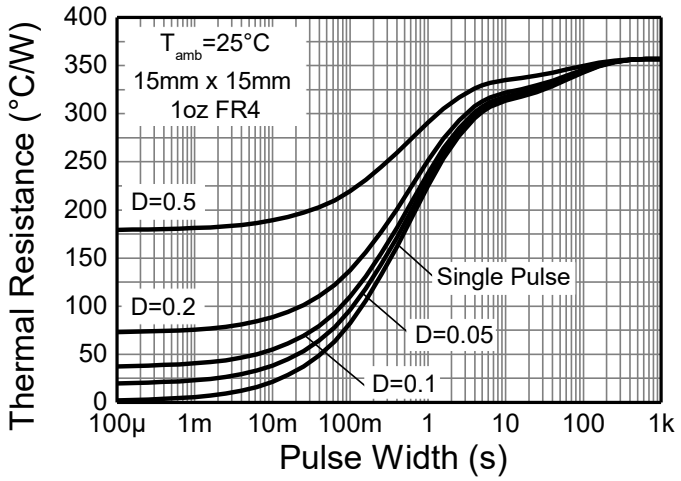


Figure 3. Transient Thermal Impedance

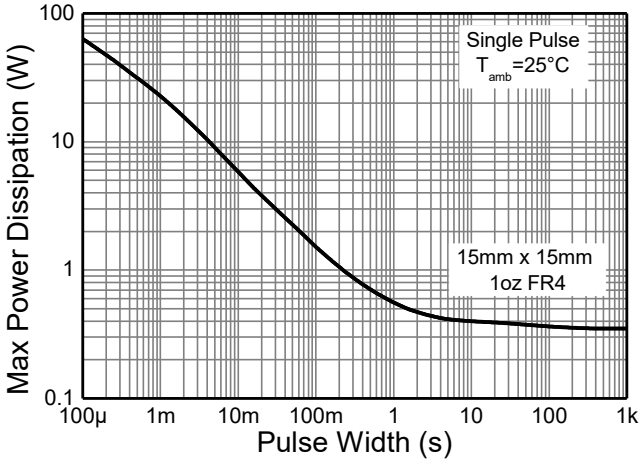


Figure 4. Pulse Power Dissipation

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	MMBTA05 MMBTA06	BV_{CBO}	60 80	— —	V	I_C = 100µA, I_E = 0
Collector-Emitter Breakdown Voltage (Note 9)	MMBTA05 MMBTA06	BV_{CEO}	60 80	— —	V	I_C = 10.0mA, I_B = 0
Emitter-Base Breakdown Voltage		BV_{EBO}	4.0	—	V	I_E = 100µA, I_C = 0
Collector Cutoff Current	MMBTA05 MMBTA06	I_{CBO}	—	100	nA	V_{CB} = 60V, I_E = 0 V_{CB} = 80V, I_E = 0
Collector Cutoff Current	MMBTA05 MMBTA06	I_{CES}	—	100	nA	V_{CE} = 60V, I_{BO} = 0 V_{CE} = 80V, I_{BO} = 0
ON CHARACTERISTICS (Note 9)						
DC Current Gain		h_{FE}	100	—	—	I_C = 10mA, V_{CE} = 1.0V I_C = 100mA, V_{CE} = 1.0V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	0.25	V	I_C = 100mA, I_B = 10mA
Base-Emitter Turn-On Voltage		$V_{BE(on)}$	—	1.2	V	I_C = 100mA, V_{CE} = 1.0V
SMALL-SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product		f_T	100	—	MHz	V_{CE} = 2.0V, I_C = 10mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

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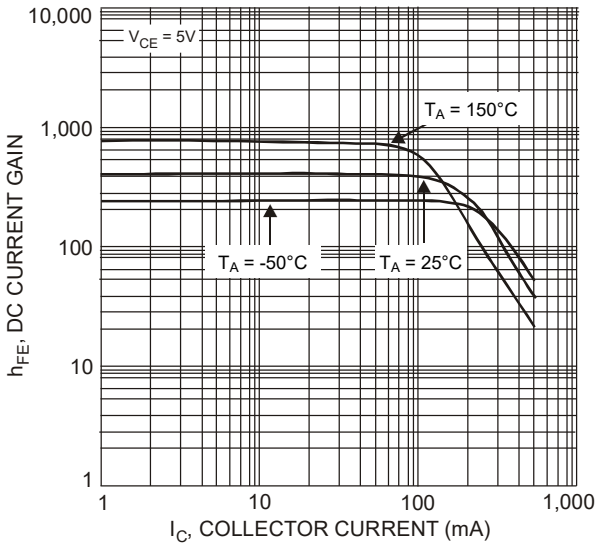


Figure 5. Typical DC Current Gain vs. Collector Current

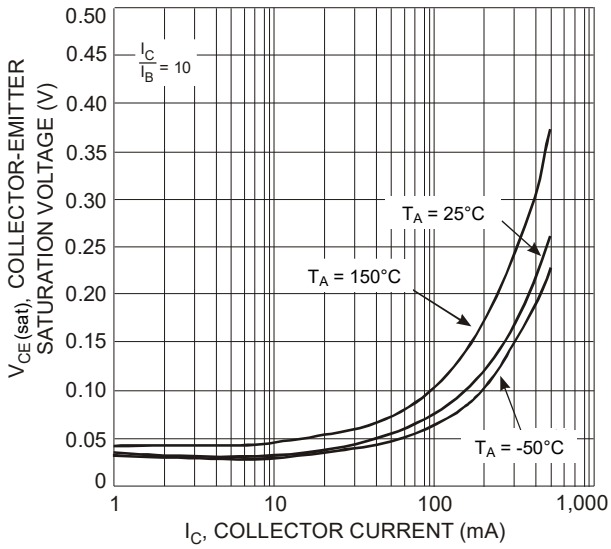


Figure 6. Collector-Emitter Saturation Voltage vs. Collector Current

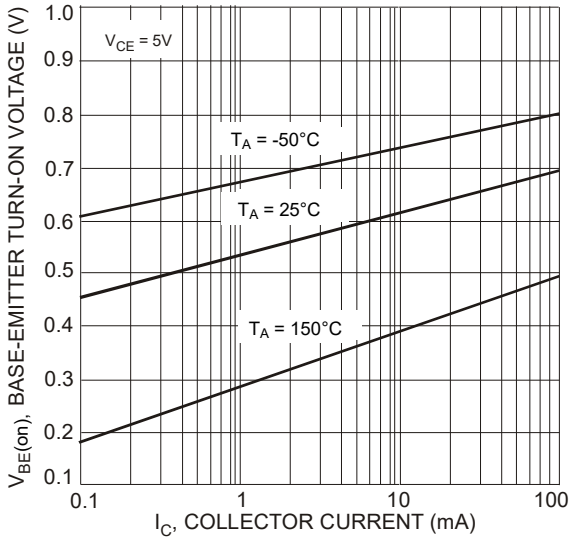


Figure 7. Typical Base-Emitter Turn-On Voltage vs. Collector Current

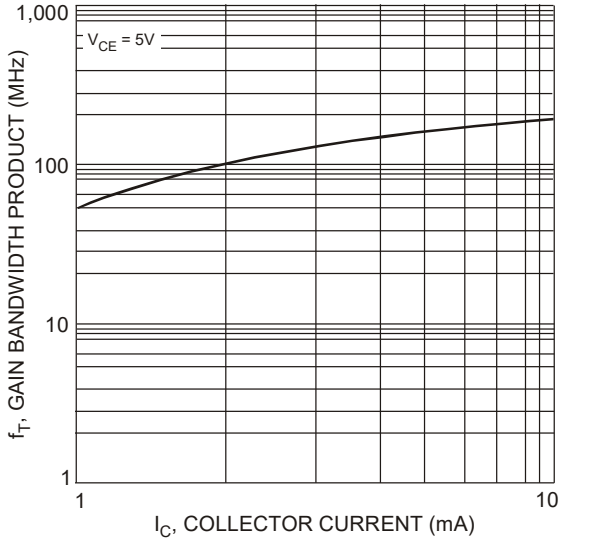


Figure 8. Typical Gain Bandwidth Product vs. Collector Current

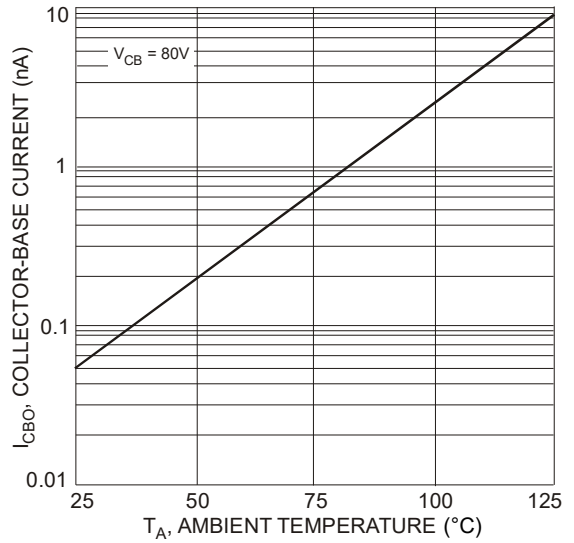


Figure 9. Typical Collector-Cutoff Current vs. Ambient Temperature

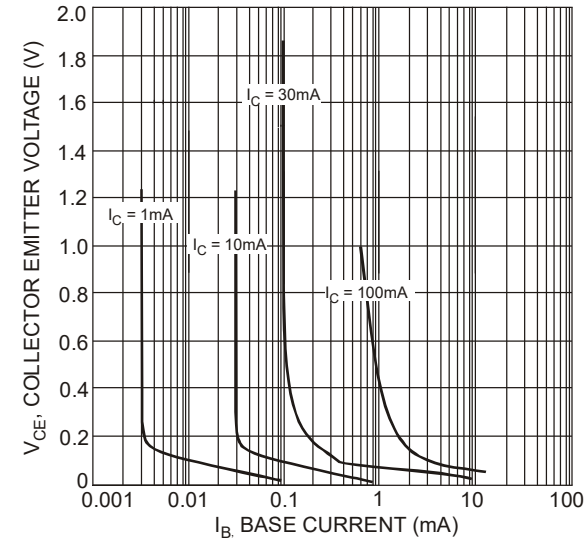


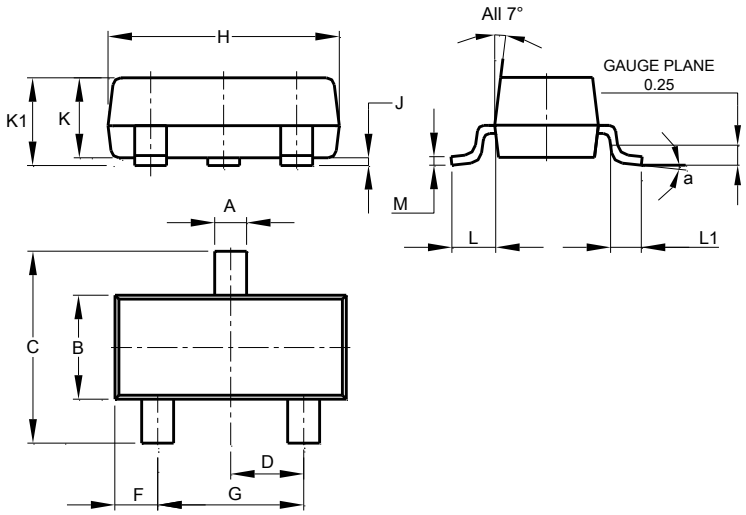
Figure 10. Typical Collector Saturation Region

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

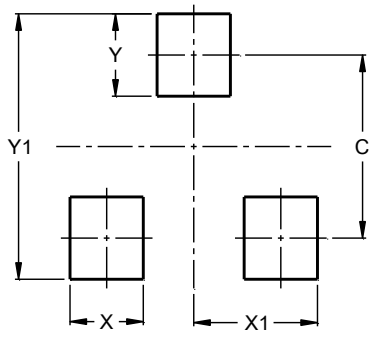


SOT23			
Dim	**Min**	**Max**	**Typ**
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
C	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9

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